

GSDxxC Series

Bidirectional TVS Diodes

DESCRIPTION

The GSDxxC Series is designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

This series has been specifically designed to protect sensitive components which are connected to power, data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events),and EFT (electrical fast transients).

FEATURES

- ♦I IEC61000-4-2 (ESD) ±30kV (Contact) ±30kV (Air)
- ♦IEC61000-4-4 (EFT) 40A (5/50ηs)
- ♦ Protects one I/O line (bidirectional)
- ♦Low clamping voltage
- ♦Working voltages:
 - 3V,5V,8V,12V,15V,18V,20V,24V,36V
- ♦Low leakage current

MACHANICAL DATA

- ♦ SOD-323 package
- ♦ Flammability Rating: UL 94V-0
- ♦Packaging: Tape and Reel
- ♦High temperature soldering guaranteed: 260°C/10s
- ♦Reel size: 7 inch
- ♦MSL 1

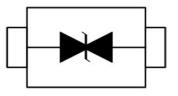
ORDERING INFORMATION

- ♦ Device: GSDxxC
- ♦Package: SOD-323
- Material: Halogen free and RoHS compliant
- ♦ Packing: Tape & Reel
- ♦Quantity per reel: 3,000pcs

APPLICATIONS

- ♦ Cell Phone Handsets and Accessories
- ♦Microprocessor based equipment
- ♦Personal Digital Assistants (PDA's)
- ♦Notebooks, Desktops, and Servers
- ♦Portable Instrumentation
- ♦Networking and Telecom
- ♦ Serial and Parallel Ports.
- \diamond Peripherals

PIN CONFIGURATION



PACKAGE OUTLINE





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ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V _{ESD}	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±30 ±30	kV				
P _{PP}	Peak Pulse Power (8/20µs)	350	W				
Торт	Operating Temperature	-55/+150	°C				
T _{STG}	Storage Temperature	-55/+150	°C				
ΤL	Lead Soldering Temperature	260 (10 sec.)	°C				

ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
PART NUMBER	DEVICE MARKING	V _{RWM} (V) (max.)	V _B (V) (min.)	I⊤ (mA)	V _C @1A (V) (max.)	۷ (/ (max.)	′c /) (@A)	Ι _R (μΑ) (max.)	C⊤ (pF) (max.)
GSD03C	2A	3.3	4.0	1	7.5	16.0	20	40	450
GSD05C	2B	5.0	6.0	1	9.8	18.0	17	10	200
GSD08C	2C	8.0	8.5	1	13.4	24.0	15	2	120
GSD12C	2D	12.0	13.3	1	19.0	32.0	11	1	75
GSD15C	2J	15.0	16.7	1	24.0	38.0	10	1	68
GSD18C	2K	18.0	20.0	1	29.0	45.0	9	1	57
GSD20C	2L	20.0	22.3	1	35.0	50.0	8	1	52
GSD24C	2H	24.0	26.7	1	43.0	52.0	7	1	50
GSD36C	2N	36.0	40.0	1	60.0	75.0	4.5	1	35



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ELECTRICAL CHARACTERISTICS CURVE Fig 1 8/20µs Waveform per IEC61000-4-5 Fig 2 Contact Discharge Current Waveform per IEC 61000-4-2) 100 Front time: T₁=1.25xT=8us Time to half-value:T₂=20us 100 90 90 Peak pulse current (%) Current (%) 50 Τ, 10 10 n 20 30ns 60ns 0 t Time (us) t, = 0.7~1ns Time (ns) Т Fig 3 Voltage vs Capacitance Fig 4 Voltage vs Capacitance 180 40 160 GSD03C 140 30 GSD18C Capacitance (pF) Capacitance (pF) 120 GSD20C GSD05C 100 20 GSD24C 80 GSD08C GSD36C 60 10 1 GSD12C 40 20 GSD15C 0 0 0.0 1.0 2.0 3.0 4.0 5.0 6.0 7.0 8.0 9.0 10.0 11.0 12.0 0.0 4.0 12.0 16.0 24.0 28.0 32.0 36.0 8.0 20.0 Voltage (V) Voltage (V) Fig 5 Clamping Voltage vs Peak Pulse Current Fig 6 Clamping Voltage vs Peak Pulse Current 20 10 t=8/20µs t=8/20µs 18 GSG 200 GSD08C 16 8 GSD03C Pulse Curent (A) Pulse Curent (A) GSD18C 14 12 6 GSD15C GSD12C 10 4 8 GSD05C Peak Peak 6 GSD24C 4 2 2 GSD36C 0 0 0 3 10 15 20 25 30 35 40 45 50 55 60 65 70 6 9 12 15 18 21 24 27 30 5 Clamping Voltage (V) Clamping Voltage (V)

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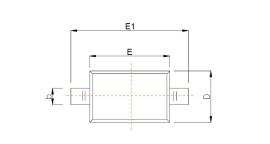
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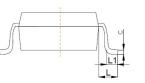
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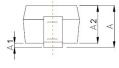


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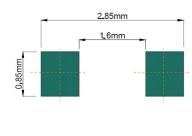
SOD-323 PACKAGE OUTLINE DIMENSIONS







Symbol	Dimensions In Millimeters			
Symbol	Min	Max		
A		1.00		
A1	0.000	0.100		
A2	0.800	0.900		
b	0.250	0.350		
с	0.080	0.150		
D	1.200	1.400		
E	1.600	1.800		
E1	2.500	2.700		
е	1.800	2.040		
L	0.475 REF			
L1	0.250	0.400		
θ	0°	8°		
e L L1	1.800 0.475 0.250	2.040 5 REF 0.400		



Recommended Pad outline

